

## isc N-Channel MOSFET Transistor

## SPD04N60S5,ISPD04N60S5

#### FEATURES

- Static drain-source on-resistance:
  - R⊳s(on)≤0.95Ω
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

Improved transconductance

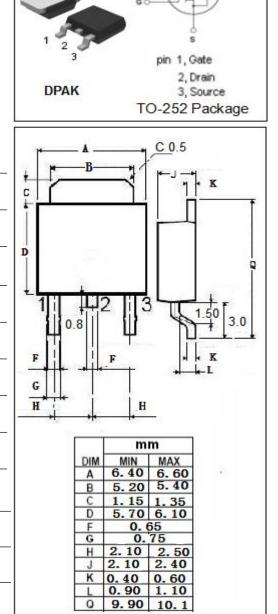
#### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	600	V			
V <sub>GS</sub>	Gate-Source Voltage	±20	20 V			
lo	Drain Current-Continuous	4.5	А			
I <sub>DM</sub>	Drain Current-Single Pulsed	9	А			
PD	Total Dissipation @Tc=25°C 50		W			
Tj	Max. Operating Junction Temperature 15		°C			
T <sub>stg</sub>	Storage Temperature	-55~150	°C			

PARAMETER

Channel-to-case thermal resistance

Channel-to-ambient thermal resistance



#### isc website: www.iscsemi.cn

THERMAL CHARACTERISTICS

SYMBOL

Rth(j-c)

Rth(j-a)

1

MAX

2.5

62

UNIT

°C/W

°C/W



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## SPD04N60S5,ISPD04N60S5

### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	600			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS=VGS; ID=0.2mA	3.5		5.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =2.8A			0.95	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V;V <sub>DS</sub> =0V			0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V			1	μ Α
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =Is, V <sub>GS</sub> = 0V			1.2	V

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